ON Semiconductor

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MBR5025L

Preferred Device

SWITCHMODE™ Power Rectifier

The SWITCHMODE power rectifier employs the use of the Schottky Barrier principle with a Platinum barrier metal. This state-of-the-art device has the following features:

- Very Low Forward Voltage Drop (Max 0.58 V @ 100°C)
- Guardring for Stress Protection and High dv/dt Capability (> 10 V/ns)
- 150°C Operating Junction Temperature
- Specially Designed for SWITCHMODE Power Supplies with Operating Frequency up to 300 kHz

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 4.3 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 30 Units Per Plastic Tube
- Marking: B5025L

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	25	V
Average Rectified Forward Current T_C = 125°C	$I_{F(AV)}$	50	A
Peak Repetitive Forward Current, (Rated V_R, Square Wave, 20 kHz @ T_C = 90°C) Per Diode	I_{FRM}	150	A
Non−Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I_{FSM}	300	A
Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz)	I_{RRM}	2.0	A
Storage Temperature Range	T_{stg}	−65 to +175	°C
Operating Junction Temperature	T_J	−65 to +150	°C
Peak Surge Junction Temperature (Forward Current Applied)	$T_{J(pk)}$	175	°C
Voltage Rate of Change	dv/dt	10,000	V/μs

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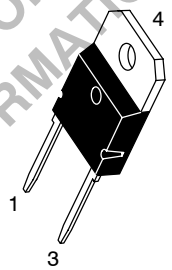
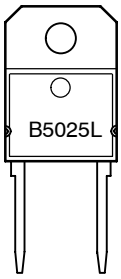
SCHOTTKY BARRIER RECTIFIER
LOW V_F
50 AMPERES
25 VOLTS



TO−218
CASE 340E
STYLE 1

MARKING DIAGRAM



B5025L = Device Code

ORDERING INFORMATION

Device	Package	Shipping
MBR5025L	TO−218	30 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Thermal Resistance — Junction to Case	$R_{\theta JC}$	0.75	°C/W

ELECTRICAL CHARACTERISTICS

Instantaneous Forward Voltage (Note 1.) @ I_F = 50 Amps, T_C = 25°C @ I_F = 50 Amps, T_C = 125°C @ I_F = 30 Amps, T_C = 25°C	V_F	 0.62 0.58 0.54	Volts
Instantaneous Reverse Current (Note 1.) @ Rated DC Voltage, T_C = 25°C @ Rated DC Voltage, T_C = 100°C	I_R	 0.5 60	mA

1. Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

TYPICAL ELECTRICAL CHARACTERISTICS

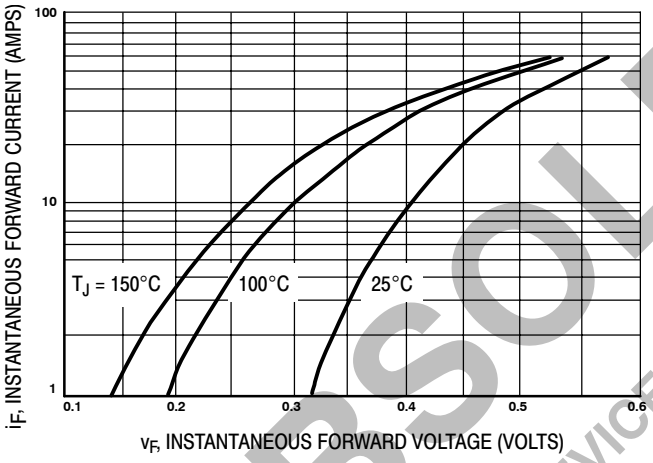


Figure 1. Typical Forward Voltage

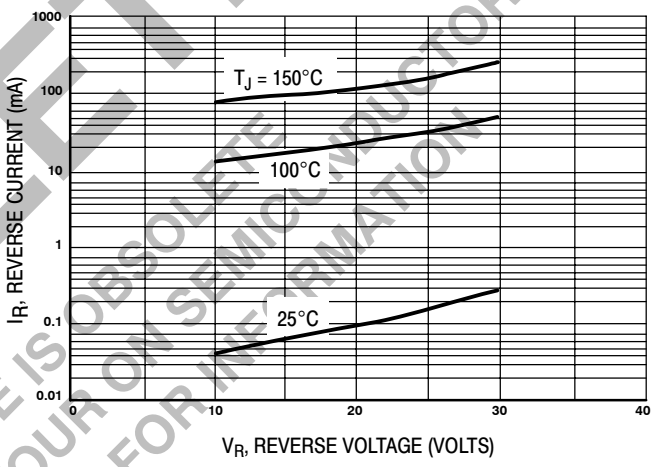


Figure 2. Typical Reverse Current

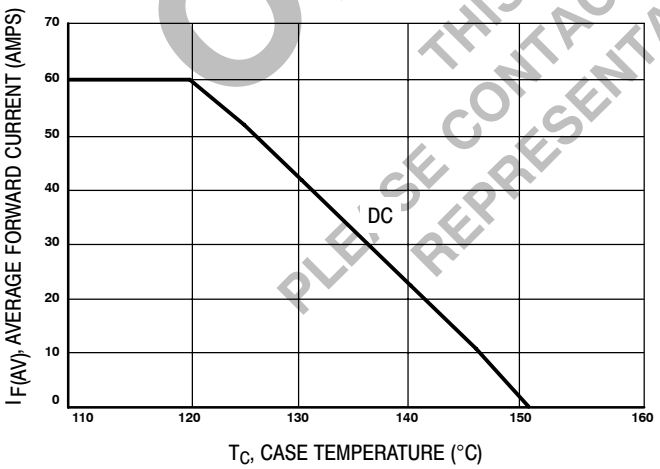


Figure 3. Current Derating, Case

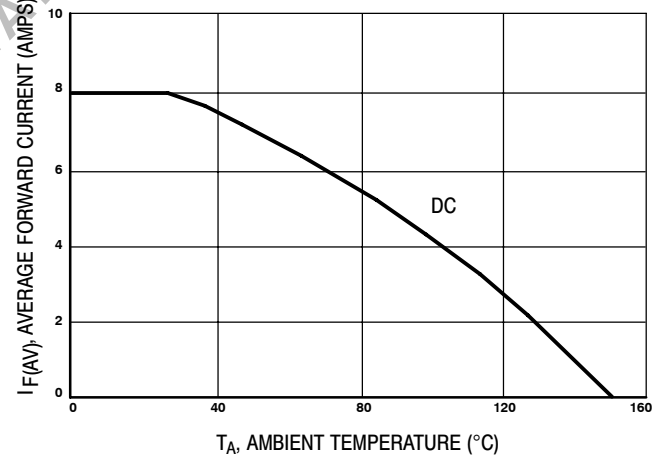
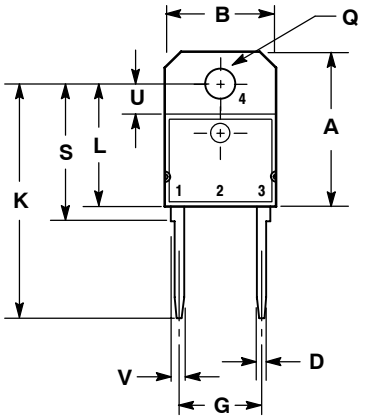
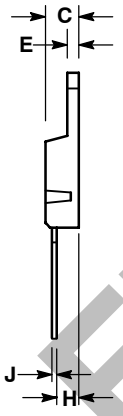


Figure 4. Current Derating, Ambient

PACKAGE DIMENSIONS

TO−218
PLASTIC
CASE 340E−02
ISSUE A





NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	---	20.35	---	0.801
B	14.70	15.20	0.579	0.598
C	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	10.80	11.10	0.425	0.437
H	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L	---	16.20	---	0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
V	1.75 REF		0.069	

STYLE 1:
PIN 1. CATHODE
3. ANODE
4. CATHODE

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PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
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MBR5025L/D